Thyristor Semiconductor Device - Page 1 of 1

AeroBase Group

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# Inclosure Material:

Metal

**Overall Length:** 

0.502 inches

# Mounting Facility Quantity:

1

### Mounting Method:

Threaded stud

#### **Overall Width Across Flats:**

0.557 inches

**Thread Size:** 

0.250 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 breakover voltage, dc

# **Current Rating Per Characteristic:**

250.00 amperes forward current, average absolute

## Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector blank

# Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

# **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

No

## Fiig:

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